

**CUS800M**

**RELIABILITY DATA**

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※ Test results are typical data. Nevertheless the following results are considered to be reference data because all units have nearly the same characteristics.

## 1. Calculated Values of MTBF

### Parts stress reliability prediction MTBF

**MODEL : CUS800M-12**

#### Calculating Method

Calculated based on parts stress reliability prediction of Telcordia (\*1).

Individual failure rate  $\lambda_{SS}$  is calculated by the electric stress and temperature rise of the each part.

\*1: Telcordia document “Reliability Prediction Procedure for Electronic Equipment”  
(Document number SR-332,Issue3)

$$\text{*Formula*} \quad MTBF = \frac{1}{\lambda_{equip}} = \frac{1}{\pi_E \sum_{i=1}^m (N_i \cdot \lambda_{ssi})} \times 10^9 \quad (\text{Hours})$$

$$\lambda_{ssi} = \lambda_{Gi} \cdot \pi_{Qi} \cdot \pi_{Si} \cdot \pi_{Ti}$$

$\lambda_{equip}$  : Total equipment failure rate (FITs = Failures in  $10^9$  hours)

$\lambda_{Gi}$  : Generic failure rate for the ith part

$\pi_{Qi}$  : Quality factor for the ith part

$\pi_{Si}$  : Stress factor for the ith part

$\pi_{Ti}$  : Temperature factor for the ith part

$m$  : Number of different part types

$N_i$  : Quantity of ith part type

$\pi_E$  : Equipment environmental factor

#### MTBF Values

##### Conditions

- Input voltage : 115VAC
- Output voltage & current : 12VDC, 56.7A
- Standby voltage & current : 5VDC, 2A
- Environmental factor : GB (Ground, Benign)
- Mounting method : Standard mounting A

SR-332,Issue3

MTBF(Ta=25°C) ≈ 755,365 (Hours)

MTBF(Ta=30°C) ≈ 632,086 (Hours)

MTBF(Ta=40°C) ≈ 425,854 (Hours)

## 1. Calculated Values of MTBF

### Parts stress reliability prediction MTBF

**MODEL : CUS800M-24**

#### Calculating Method

Calculated based on parts stress reliability prediction of Telcordia (\*1).

Individual failure rate  $\lambda_{SS}$  is calculated by the electric stress and temperature rise of the each part.

\*1: Telcordia document “Reliability Prediction Procedure for Electronic Equipment”  
(Document number SR-332,Issue3)

$$\text{*Formula*} \quad MTBF = \frac{1}{\lambda_{equip}} = \frac{1}{\pi_E \sum_{i=1}^m (N_i \cdot \lambda_{ssi})} \times 10^9 \quad (\text{Hours})$$

$$\lambda_{ssi} = \lambda_{Gi} \cdot \pi_{Qi} \cdot \pi_{Si} \cdot \pi_{Ti}$$

$\lambda_{equip}$  : Total equipment failure rate (FITs = Failures in  $10^9$  hours)

$\lambda_{Gi}$  : Generic failure rate for the ith part

$\pi_{Qi}$  : Quality factor for the ith part

$\pi_{Si}$  : Stress factor for the ith part

$\pi_{Ti}$  : Temperature factor for the ith part

$m$  : Number of different part types

$N_i$  : Quantity of ith part type

$\pi_E$  : Equipment environmental factor

#### MTBF Values

##### Conditions

- Input voltage : 115VAC
- Output voltage & current : 24VDC, 33.4A
- Standby voltage & current : 5VDC, 2A
- Environmental factor : GB (Ground, Benign)
- Mounting method : Standard mounting A

SR-332,Issue3

MTBF(Ta=25°C) ≈ 805,502 (Hours)

MTBF(Ta=30°C) ≈ 674,511 (Hours)

MTBF(Ta=40°C) ≈ 452,227 (Hours)

## 2. Components Derating

**MODEL : CUS800M-12**

### (1) Calculating Method

(a) Measuring method

• Mounting method	: Standard mounting A	• Input voltage	: 115, 230VAC
• Output voltage & current	: 12V, 56.7A	• Ambient temperature	: 40°C
• Standby voltage & current	: 5V, 2A		

(b) Semiconductors

Compared with maximum junction temperature and actual one which is calculated based on case temperature, power dissipation and thermal impedance.

(c) IC, Resistors, Capacitors, etc.

Ambient temperature, operating condition, power dissipation and so on are within derating criteria.

(d) Calculating method of thermal impedance

$$\theta_{j-c} = \frac{T_{j(max)} - T_c}{P_{ch(max)}} \quad \theta_{j-a} = \frac{T_{j(max)} - T_a}{P_{ch(max)}} \quad \theta_{j-l} = \frac{T_{j(max)} - T_l}{P_{ch(max)}}$$

T<sub>c</sub> : Case Temperature at Start Point of Derating; 25°C in General

T<sub>a</sub> : Ambient Temperature at Start Point of Derating; 25°C in General

T<sub>l</sub> : Lead Temperature at Start Point of Derating; 25°C in General

P<sub>ch(max)</sub> : Maximum Channel Dissipation

T<sub>j(max)</sub> : Maximum Junction (channel) Temperature  
(T<sub>ch(max)</sub>)

$\theta_{j-c}$  : Thermal Impedance between Junction (channel) and Case  
( $\theta_{ch-c}$ )

$\theta_{j-a}$  : Thermal Impedance between Junction and air

$\theta_{j-l}$  : Thermal Impedance between Junction and Lead

## (2) Component Derating List

Location No.	Measurement condition			
	Vin = 115VAC	Iout = 56.7A	Istb = 2A	Ta = 40°C
BD1 D25XB80-7000 SHINDENGEN	Tch (max) = 150 °C Pch= 9.1 W Tch = Tc + ((θch-c) × Pch) = 89.1 °C D.F. = 59.4 %	θch-c = 1.0 °C/W ΔTc = 40 °C Tc = 80 °C		
SCR1 TN1605H-6FP STMICRO	Tch (max) = 150 °C Pch = 3.06 W Tch = Tc + ((θch-c) × Pch ) = 88.3 °C D.F. = 58.8 %	θch-c = 4.5 °C/W ΔTc = 34.5 °C Tc = 74.5 °C		
D1 TRS10A65F,S1Q TOSHIBA	Tch (max) = 175 °C Pch= 2.3 W Tch = Tc + ((θch-c) × Pch ) = 92.7 °C D.F. = 53.0 %	θch-c = 3.78 °C/W ΔTc = 44.0 °C Tc = 84 °C		
Q1 TK39N60W,S1VF TOSHIBA	Tj (max) = 150 °C Pd = 6.8 W Tj = Tc + ((θj-c) × Pd ) = 79.6 °C D.F. = 53.1 %	θj-c = 0.463 °C/W ΔTc = 36.5 °C Tc = 76.5 °C		
Q103,Q104 IPT60R090CFD7 INFINEON	Tj (max) = 150 °C Pd = 3.3 W Tj = Tc + ((θj-c) × Pd ) = 80.4 °C D.F. = 53.6 %	θj-c = 0.78 °C/W ΔTc = 37.8 °C Tc = 77.8 °C		
D61 SB360-E3/73 VISHAY	Tj (max) = 150 °C Pd = 0.9 W Tj = Tl + ((θj-l) × Pd ) = 108.2 °C D.F. = 72.1 %	θj-l = 10 °C/W ΔTl = 59.2 °C Tl = 99.2 °C		
Q301,Q303 TPH1R306PL,L1Q TOSHIBA	Tj (max) = 175 °C Pd = 3.6 W Tj = Tc + ((θj-c) × Pd ) = 114.9 °C D.F. = 65.6 %	θj-c = 0.88 °C/W ΔTc = 71.7 °C Tc = 111.7 °C		

## Terminology Used

Vin : Input Voltage  
 Istb : Output current of standby

Iout : Output Current  
 Ta : Ambient temperature

## (2) Component Derating List

Location No.	Measurement condition Vin = 230VAC      Iout = 56.7A      Istb = 2A      Ta = 40°C			
BD1 D25XB80-7000 SHINDENGEN	Tch (max) = 150 °C Pch= 4.45 W Tch = Tc + ((θch-c) × Pch) = 65.4 °C D.F. = 43.6 %	θch-c = 1.0 °C/W ΔTc = 20.9 °C Tc = 60.9 °C		
SCR1 TN1605H-6FP STMICRO	Tch (max) = 150 °C Pch = 3.0 W Tch = Tc + ((θch-c) × Pch ) = 74.4 °C D.F. = 49.6 %	θch-c = 4.5 °C/W ΔTc = 20.9 °C Tc = 60.9 °C		
D1 TRS10A65F,S1Q TOSHIBA	Tch (max) = 175 °C Pch= 1.5 W Tch = Tc + ((θch-c) × Pch ) = 73.0 °C D.F. = 41.7 %	θch-c = 3.78 °C/W ΔTc = 27.3 °C Tc = 67.3 °C		
Q1 TK39N60W,S1VF TOSHIBA	Tj (max) = 150 °C Pd = 3.2 W Tj = Tc + ((θj-c) × Pd ) = 61.3 °C D.F. = 40.9 %	θj-c = 0.463 °C/W ΔTc = 19.8 °C Tc = 59.8 °C		
Q103,Q104 IPT60R090CFD7 INFINEON	Tj (max) = 150 °C Pd = 3.3 W Tj = Tc + ((θj-c) × Pd ) = 74.2 °C D.F. = 49.4 %	θj-c = 0.78 °C/W ΔTc = 31.6 °C Tc = 71.6 °C		
D61 SB360-E3/73 VISHAY	Tj (max) = 150 °C Pd = 0.9 W Tj = Tl + ((θj-l) × Pd ) = 103.4°C D.F. = 68.9 %	θj-l = 10 °C/W ΔTl = 54.4 °C Tl = 94.4 °C		
Q301,Q303 TPH1R306PL,L1Q TOSHIBA	Tj (max) = 175 °C Pd = 3.6 W Tj = Tc + ((θj-c) × Pd ) = 107.3 °C D.F. = 61.3 %	θj-c = 0.88 °C/W ΔTc = 64.1 °C Tc = 104.1 °C		

## Terminology Used

Vin : Input Voltage  
Istb : Output current of standby

Iout : Output Current  
Ta : Ambient temperature

## 2. Components Derating

**MODEL : CUS800M-24**

### (1) Calculating Method

(a) Measuring method

• Mounting method	: Standard mounting A	• Input voltage	: 115, 230VAC
• Output voltage & current	: 24V, 33.4A	• Ambient temperature	: 40°C
• Standby voltage & current	: 5V, 2A		

(b) Semiconductors

Compared with maximum junction temperature and actual one which is calculated based on case temperature, power dissipation and thermal impedance.

(c) IC, Resistors, Capacitors, etc.

Ambient temperature, operating condition, power dissipation and so on are within derating criteria.

(d) Calculating method of thermal impedance

$$\theta_{j-c} = \frac{T_{j(max)} - T_c}{P_{ch(max)}} \quad \theta_{j-a} = \frac{T_{j(max)} - T_a}{P_{ch(max)}} \quad \theta_{j-l} = \frac{T_{j(max)} - T_l}{P_{ch(max)}}$$

T<sub>c</sub> : Case Temperature at Start Point of Derating; 25°C in General

T<sub>a</sub> : Ambient Temperature at Start Point of Derating; 25°C in General

T<sub>l</sub> : Lead Temperature at Start Point of Derating; 25°C in General

P<sub>ch(max)</sub> : Maximum Channel Dissipation

T<sub>j(max)</sub> : Maximum Junction (channel) Temperature  
(T<sub>ch(max)</sub>)

$\theta_{j-c}$  : Thermal Impedance between Junction (channel) and Case  
( $\theta_{ch-c}$ )

$\theta_{j-a}$  : Thermal Impedance between Junction and air

$\theta_{j-l}$  : Thermal Impedance between Junction and Lead

## (2) Component Derating List

Location No.	Measurement condition		
	Vin = 115VAC	Iout = 33.4A	Istb = 2A
BD1 D25XB80-7000 SHINDENGEN	Tch (max) = 150 °C Pch= 12 W Tch = Tc + ((θch-c) × Pch) = 99.2 °C D.F. = 66.1 %	θch-c = 1.0 °C/W ΔTc = 47.2 °C Tc = 87.2 °C	
SCR1 TN1605H-6FP STMICRO	Tch (max) = 150 °C Pch = 3.27 W Tch = Tc + ((θch-c) × Pch) = 102.7 °C D.F. = 68.5 %	θch-c = 4.5 °C/W ΔTc = 48 °C Tc = 88 °C	
D1 TRS10A65F,S1Q TOSHIBA	Tch (max) = 175 °C Pch= 2.7 W Tch = Tc + ((θch-c) × Pch) = 102.3 °C D.F. = 58.5 %	θch-c = 3.78 °C/W ΔTc = 52.1 °C Tc = 92.1 °C	
Q1 TK39N60W,S1VF TOSHIBA	Tj (max) = 150 °C Pd = 8.4 W Tj = Tc + ((θj-c) × Pd) = 91.3 °C D.F. = 60.9 %	θj-c = 0.463 °C/W ΔTc = 47.4 °C Tc = 87.4 °C	
Q103,Q104 IPT60R090CFD7 INFINEON	Tj (max) = 150 °C Pd = 3.67 W Tj = Tc + ((θj-c) × Pd) = 101.3 °C D.F. = 67.5 %	θj-c = 0.78 °C/W ΔTc = 58.4 °C Tc = 98.4 °C	
D61 SB360-E3/73 VISHAY	Tj (max) = 150 °C Pd = 0.9 W Tj = Tl + ((θj-l) × Pd) = 105.7 °C D.F. = 70.5 %	θj-l = 10 °C/W ΔTl = 56.7 °C Tl = 96.7 °C	
Q301,Q303 TPH2R408QM,LQ(M1) TOSHIBA	Tj (max) = 175 °C Pd = 2.27W Tj = Tc + ((θj-c) × Pd) = 107.5 °C D.F. = 61.4 %	θj-c = 0.71 °C/W ΔTc = 65.9 °C Tc = 105.9 °C	

## Terminology Used

Vin : Input Voltage  
 Istb : Output current of standby

Iout : Output Current  
 Ta : Ambient temperature

## (2) Component Derating List

Location No.	Measurement condition		
	Vin = 230VAC	Iout = 33.4A	Istb = 2A
BD1 D25XB80-7000 SHINDENGEN	Tch (max) = 150 °C Pch= 6 W Tch = Tc + ((θch-c) × Pch) = 70 °C D.F. = 46.7 %	θch-c = 1.0 °C/W ΔTc = 24 °C Tc = 64 °C	
SCR1 TN1605H-6FP STMICRO	Tch (max) = 150 °C Pch = 3.2 W Tch = Tc + ((θch-c) × Pch ) = 83.4 °C D.F. = 55.6 %	θch-c = 4.5 °C/W ΔTc = 29 °C Tc = 69 °C	
D1 TRS10A65F,S1Q TOSHIBA	Tch (max) = 175 °C Pch= 1.6 W Tch = Tc + ((θch-c) × Pch ) = 76.9 °C D.F. = 44.0 %	θch-c = 3.78 °C/W ΔTc = 30.9 °C Tc = 70.9 °C	
Q1 TK39N60W,S1VF TOSHIBA	Tj (max) = 150 °C Pd = 5.6 W Tj = Tc + ((θj-c) × Pd ) = 67.3 °C D.F. = 44.9 %	θj-c = 0.463 °C/W ΔTc = 24.7 °C Tc = 64.7 °C	
Q103,Q104 IPT60R090CFD7 INFINEON	Tj (max) = 150 °C Pd = 3.67 W Tj = Tc + ((θj-c) × Pd ) = 92.5 °C D.F. = 61.6 %	θj-c = 0.78 °C/W ΔTc = 49.6 °C Tc = 89.6 °C	
D61 SB360-E3/73 VISHAY	Tj (max) = 150 °C Pd = 0.9 W Tj = Tl + ((θj-l) × Pd ) = 96.2 °C D.F. = 64.1 %	θj-l = 10 °C/W ΔTl = 47.2 °C Tl = 87.2 °C	
Q301,Q303 TPH2R408QM,LQ(M1) TOSHIBA	Tj (max) = 175 °C Pd = 2.27 W Tj = Tc + ((θj-c) × Pd ) = 98.7 °C D.F. = 56.4 %	θj-c = 0.71 °C/W ΔTc = 57.1 °C Tc = 97.1 °C	

## Terminology Used

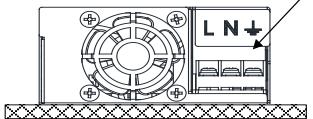
Vin : Input Voltage  
 Istb : Output current of standby

Iout : Output Current  
 Ta : Ambient temperature

### 3. Main Components Temperature Rise $\Delta T$ List

MODEL : CUS800M-12

#### (1) Measuring Conditions

Mounting Method  (Standard Mounting : A)	Mounting A (STANDARD MOUNTING)	
	 INPUT TERMINAL	
Input Voltage	115VAC	230VAC
Output Voltage	12V	
Output Current	56.7A	
Standby Current	2A	
Ambient Temperature	40°C	

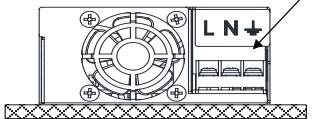
#### (2) Measuring Results

		$\Delta T$ Temperature Rise (°C)	
Input Voltage		115VAC	230VAC
Location No.	Part name	Mounting A	
BD1	Diode Bridge	40	20.9
C51A	E.CAP.	42.8	36.2
C51C	E.CAP.	42.1	35.2
C52A	E.CAP.	40.5	34.4
C52B	E.CAP.	49.2	42.9
C8B	E.CAP.	15.3	9.4
C8C	E.CAP.	18.7	12.7
D1	SBD	44	27.3
L3	CHOKE COIL	30.4	18.6
Q1	MOS FET	36.5	19.8
Q103	MOS FET	37.8	31.6
Q104	MOS FET	36.9	31.5
Q301	MOS FET	71.7	64.1
Q303	MOS FET	66.4	59.1
SCR1	Thyristor	34.5	20.9
T1	TRANS	73.8	66.5
TH101	Thermistor(PTC)	34.7	29.2
TH2	Thermistor(PTC)	35.2	20.5
TH301	Thermistor(PTC)	66.1	59.1

### 3. Main Components Temperature Rise $\Delta T$ List

MODEL : CUS800M-24

#### (1) Measuring Conditions

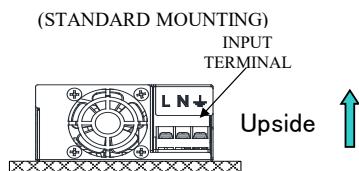
Mounting Method  (Standard Mounting : A)	Mounting A (STANDARD MOUNTING)	
	 INPUT TERMINAL	
Input Voltage	115VAC	230VAC
Output Voltage	24V	
Output Current	33.4A	
Standby Current	2A	
Ambient Temperature	40°C	

#### (2) Measuring Results

		$\Delta T$ Temperature Rise (°C)	
Input Voltage		115VAC	230VAC
Location No.	Part name	Mounting A	
BD1	Diode Bridge	47.2	24
C51A	E.CAP.	33.8	26.1
C51B	E.CAP.	34.1	26.9
C51C	E.CAP.	34.4	27.4
C52B	E.CAP.	34.2	27.4
C8B	E.CAP.	19.7	11.8
C8C	E.CAP.	22.7	14.5
D1	SBD	52.1	30.9
L3	CHOKE COIL	34.2	18.7
Q1	MOS FET	47.4	24.7
Q103	MOS FET	55.4	45.8
Q104	MOS FET	58.4	49.6
Q301	MOS FET	63.9	55.2
Q303	MOS FET	65.9	57.1
SCR1	Thyristor	48	29
T1	TRANS	68.4	59.9
TH101	Thermistor(PTC)	50.1	41.9
TH2	Thermistor(PTC)	44.5	24.9
TH301	Thermistor(PTC)	61.4	52.7

#### 4. Electrolytic Capacitor Lifetime

MODEL : CUS800M-12

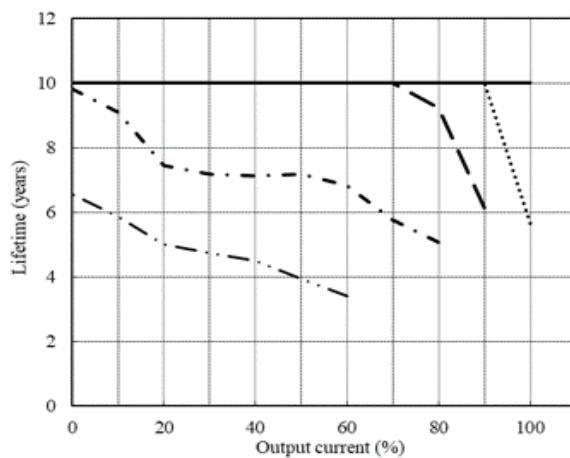


Conditions

Istb :	2A (Ta ≤ 60°C)
	1.6A (Ta = 70°C)
Ta	30°C : _____
	40°C : .....
	50°C : - - -
	60°C : - . - -
	70°C : - - - -

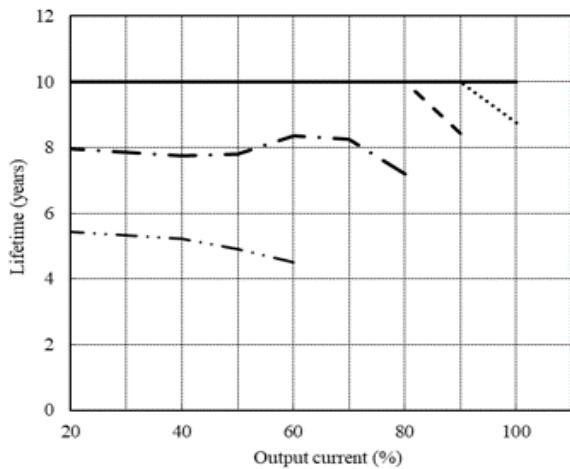
Vin=115VAC

Load (%)	Lifetime (years)				
	Ta= 30°C	Ta= 40°C	Ta= 50°C	Ta= 60°C	Ta= 70°C
100	10	5.7	-	-	-
90	10	10	6.1	-	-
80	10	10	9.2	5.1	-
60	10	10	10	6.8	3.4
40	10	10	10	7.1	4.5
20	10	10	10	7.4	5.0
0	10	10	10	9.8	6.6



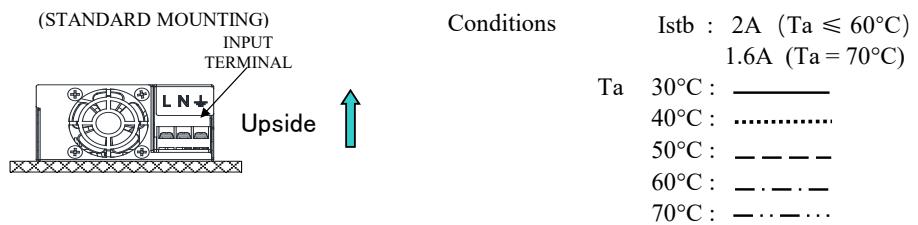
Vin=230VAC

Load (%)	Lifetime (years)				
	Ta= 30°C	Ta= 40°C	Ta= 50°C	Ta= 60°C	Ta= 70°C
100	10	8.7	-	-	-
90	10	10	8.4	-	-
80	10	10	10	7.2	-
60	10	10	10	8.4	4.5
40	10	10	10	7.8	5.2
20	10	10	10	8.0	5.4
0	10	10	10	9.9	6.6



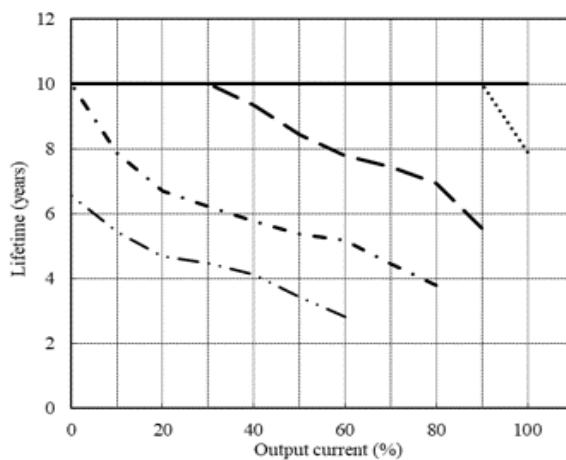
#### 4. Electrolytic Capacitor Lifetime

MODEL : CUS800M-24



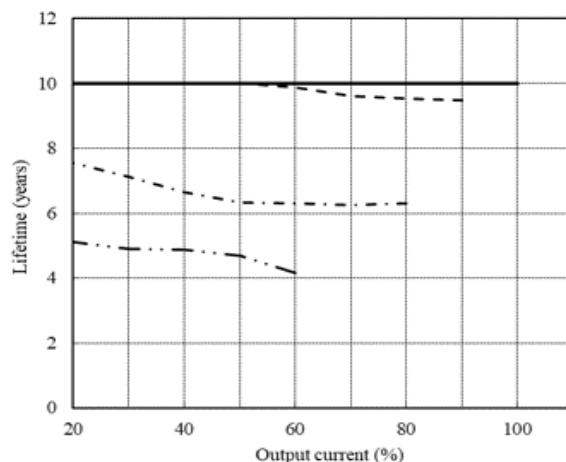
Vin=115VAC

Load (%)	Lifetime (years)				
	Ta= 30°C	Ta= 40°C	Ta= 50°C	Ta= 60°C	Ta= 70°C
100	10	7.9	-	-	-
90	10	10	5.6	-	-
80	10	10	7.0	3.8	-
60	10	10	7.8	5.2	2.8
40	10	10	9.3	5.8	4.1
20	10	10	10	6.7	4.7
0	10	10	10	10	6.6



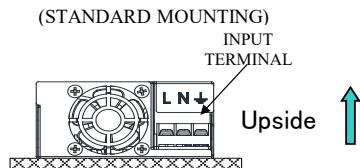
Vin=230VAC

Load (%)	Lifetime (years)				
	Ta= 30°C	Ta= 40°C	Ta= 50°C	Ta= 60°C	Ta= 70°C
100	10	10	-	-	-
90	10	10	9.5	-	-
80	10	10	9.5	6.3	-
60	10	10	9.9	6.3	4.2
40	10	10	10	6.7	4.9
20	10	10	10	7.5	5.1
0	10	10	10	10	6.8



#### 4. Electrolytic Capacitor Lifetime

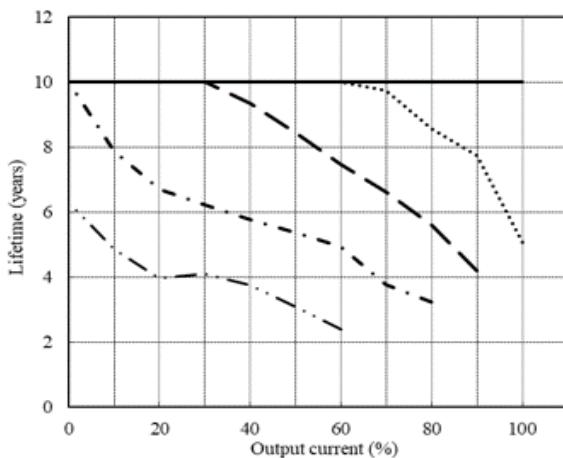
**MODEL : CUS800M-36**



Conditions	
Istb :	2A ( $T_a \leq 60^\circ\text{C}$ )
	1.6A ( $T_a = 70^\circ\text{C}$ )
Ta	30°C : _____
	40°C : .....
	50°C : - - -
	60°C : - . - -
	70°C : - - - -

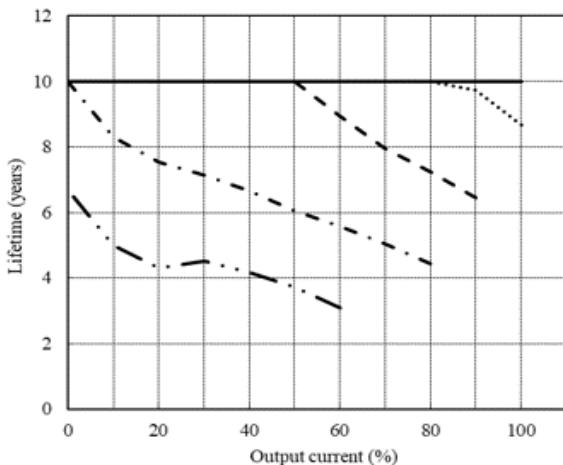
Vin=115VAC

Load (%)	Lifetime (years)				
	Ta= 30°C	Ta= 40°C	Ta= 50°C	Ta= 60°C	Ta= 70°C
100	10	5.1	-	-	-
90	10	7.7	4.2	-	-
80	10	8.6	5.6	3.2	-
60	10	10	7.5	4.9	2.4
40	10	10	9.3	5.8	3.8
20	10	10	10	6.7	4.0
0	10	10	10	10	6.3



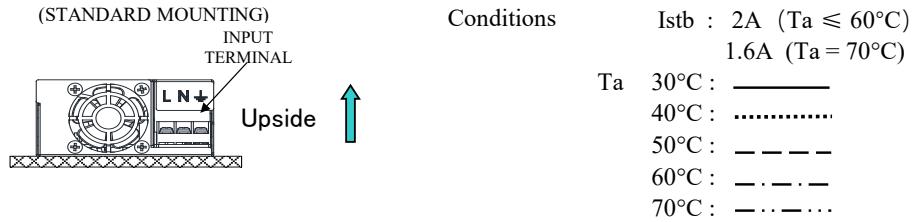
Vin=230VAC

Load (%)	Lifetime (years)				
	Ta= 30°C	Ta= 40°C	Ta= 50°C	Ta= 60°C	Ta= 70°C
100	10	8.7	-	-	-
90	10	9.7	6.5	-	-
80	10	10	7.2	4.4	-
60	10	10	8.9	5.6	3.1
40	10	10	10	6.7	4.2
20	10	10	10	7.5	4.3
0	10	10	10	10	6.7



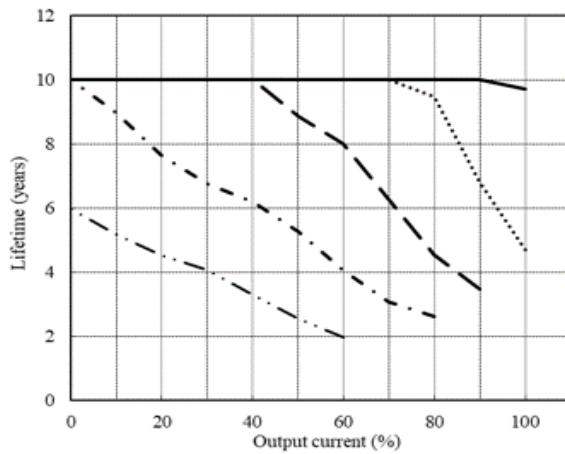
#### 4. Electrolytic Capacitor Lifetime

**MODEL : CUS800M-48**



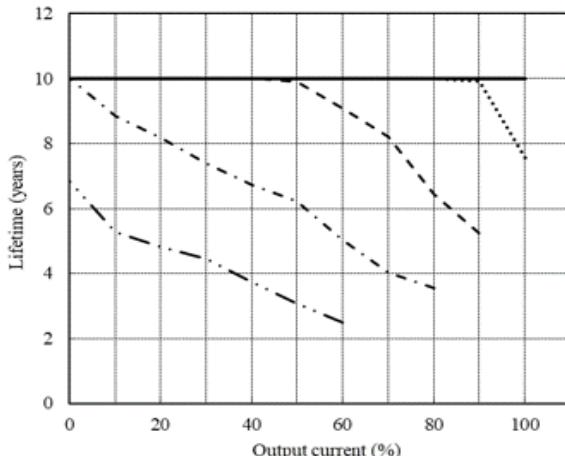
Vin=115VAC

Load (%)	Lifetime (years)				
	Ta= 30°C	Ta= 40°C	Ta= 50°C	Ta= 60°C	Ta= 70°C
100	9.7	4.7	-	-	-
90	10	6.8	3.5	-	-
80	10	9.5	4.5	2.6	-
60	10	10	8.0	4.1	2.0
40	10	10	10	6.2	3.3
20	10	10	10	7.6	4.5
0	10	10	10	10	6.0



Vin=230VAC

Load (%)	Lifetime (years)				
	Ta= 30°C	Ta= 40°C	Ta= 50°C	Ta= 60°C	Ta= 70°C
100	10	7.6	-	-	-
90	10	9.9	5.2	-	-
80	10	10	6.4	3.5	-
60	10	10	9.1	5.0	2.5
40	10	10	10	6.7	3.7
20	10	10	10	8.2	4.8
0	10	10	10	10	6.8



## 5. Abnormal Test

MODEL : CUS800M-24

### (1) Test Conditions

Input : 230VAC Output : 24V, 33.4A Istb : 2A Ta : 25°C

### (2) Test Results

(Da:Damaged)

No.	Test position		Test mode	Test result														Note	
	Location No.	Test point		Short	Open	a Fire	b Slight Smoke	c Smoke	d Burst	e Smell	f Red hot	g Damaged	h Fuse blown	i O.V.P.	j O.C.P.	k No output	l No change	Others	
1	SCR1	A	O															O	Input Power increase 5W
		K	O															O	Input Power increase 5W
		G	O															O	Input Power increase 5W
		A-K	O															O	Input Power decrease 3.5W
		A-G	O															O	
		G-K	O															O	Input Power increase 5W
2	Q1	G	O															O	
		D	O															O	
		S	O															O	
		G-S	O															O	
		G-D	O															O	Da:F1A,F1B,Q1,R104,A102,R106,R107,Z101,Q102
		D-S	O															O	Da:F1A,F1B,R104
3	D1		O															O	
			O															O	Da:F1A,F1B,Q1,SCR1,R104,A102,R112,R113,Q101
4	L4		O															O	
			O															O	Da:F1B,Q1,R104
5	C1, C2		O															O	
			O															O	
6	SA1		O															O	Da: F1A, F1B
			O															O	
7	C7		O															O	Da:F1A,F1B
			O															O	Input Power increase 3W
8	BD1	1	O															O	
		2	O															O	
		3	O															O	
		4	O															O	
		1~2	O															O	Da: F1A, F1B
		2~3	O															O	Da: F1A, F1B
		3~4	O															O	Da: F1A, F1B
		1~4	O															O	Da: F1A, F1B
		G	O															O	Da:Q103,Q104,F3
9	Q103	D	O															O	Da:Q103,Q104,F3,A107
		S	O															O	Da:Q103,Q104,F3,A106
		G-S	O															O	
		G-D	O															O	Da:Q103,Q104,F3,A106
		D-S	O															O	Da:Q104,F3
		G	O															O	Da:F3,Q103,Q104
10	Q104	D	O															O	
		S	O															O	
		G-S	O															O	
		G-D	O															O	
		D-S	O															O	Da:F3,Q103

## 5. Abnormal Test

MODEL : CUS800M-24

### (1) Test Conditions

Input : 230VAC Output : 24V, 33.4A Istb : 2A Ta : 25°C

### (2) Test Results

(Da:Damaged)

No.	Test position		Test mode	Test result													Note	
	Location No.	Test point		Short	Open	a	b	c	d	e	f	g	h	i	j	k	l	
						Fire	Slight Smoke	Smoke	Burst	Smell	Red hot	Damaged	Fuse blown	O.V.P.	O.C.P.	No output	No change	Others
11	T2	2		○											○	Standby power :No output		
		3		○											○	Standby power :No output		
		5		○											○	Standby power :No output		
		6		○											○	Standby power :No output		
		7		○											○	Standby power hiccup		
		8		○											○	Standby power hiccup		
		2~3	○												○	Standby power hiccup & OCP		
		5~6	○												○	Standby power :No output		
		6~7	○							○	○				○	Da:F2, Standby power :No output		
		7~8	○												○	Standby power hiccup & OCP		
12	Q301	d		○											○	Input Power increase 1.5W		
		s		○											○	Input Power increase 1.5W		
		g		○						○					○	Da: Q301		
		d~s	○									○	○					
		g~s	○												○	Input Power increase 16W, Main power is OTP		
		g~d	○							○		○			○	DA:A301		
13	Q303	d		○											○	Input Power increase 1.5W		
		s		○											○	Input Power increase 1.5W		
		g		○						○					○	Da: Q303		
		d~s	○										○	○				
		g~s	○												○	Input Power increase 16W, Main power is OTP		
		g~d	○							○		○			○	DA:A301		
14	T1	1		○											○			
		4		○											○			
		2		○											○			
		3		○											○			
		5~8	○												○			
		1~4	○												○			
		2~3	○												○			
		5~8	○												○			

## 6. Vibration Test

MODEL : CUS800M-12/24/36/48

### (1) Vibration Test Class

Frequency variable endurance test

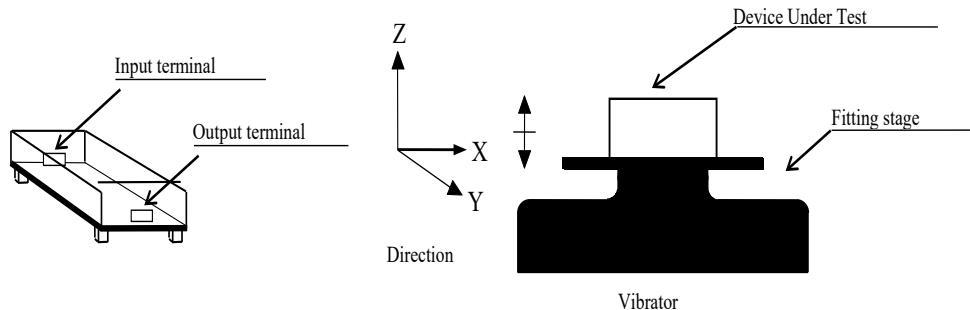
### (2) Equipment Used

IMV CORP. DC-3200-36

### (3) Test Conditions

· Sweep frequency	: 10~55Hz	· Direction	: X, Y, Z
· Sweep time	: 1.0min	· Sweep count	: 1 hour each
· Acceleration			: Constant $19.6\text{m/s}^2$ (2G)

### (4) Test Method



### (5) Acceptable Conditions

1. Not to be broken
2. No abnormal output after test.

### (6) Test Results

Judgement :      OK

## 7. Noise Simulate Test

**MODEL : CUS800M-12/24/36/48**

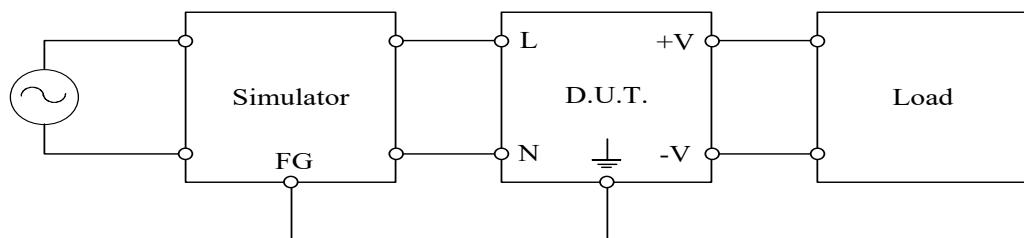
### (1) Equipment Used

Simulator : INS-400L (Noise Laboratory Co.,LTD)

Capacitive Coupling Adaptors : CA-805B

### (2) Test Method and Device Test Point

Apply to (N, L,  $\frac{1}{\sqrt{2}}$ ), (N, L), (N), (L), ( $\frac{1}{\sqrt{2}}$ ), (V+, V-), (STBY+, STBY-), (R+, R-), (S+, S-), (PG)



### (3) Test Conditions

- |                       |               |                   |   |
|-----------------------|---------------|-------------------|---|
| • Input voltage       | : 100, 230VAC | • Noise level     | : 0~2kV(Input Port)<br>: 0~2kV(Output Port)           |
| • Output voltage      | : Rated       |                   | : 0~750V(Signal Port)                                 |
| • Output current      | : 0%, 100%    | • Standby current | : 0%, 100%  |
| • Polarity            | : +, -        | • Mode            | : Common, Normal(Input Port)<br>: Common(Output Port) |
| • Ambient temperature | : 25°C        |                   | : Common(Signal Port)                                 |
| • Pulse width         | : 50~1000ns   | • Trigger select  | : Line  |
| • Phase               | : 0~360 deg   |                   |   |

### (4) Acceptable Conditions

1. The regulation of output voltage must not exceed 5% of initial value during test.
2. The output voltage must be within the regulation of specification after the test.
3. Smoke and fire are not allowed.

### (5) Test Results

Judgement : **OK**

## 8. Thermal Shock Test

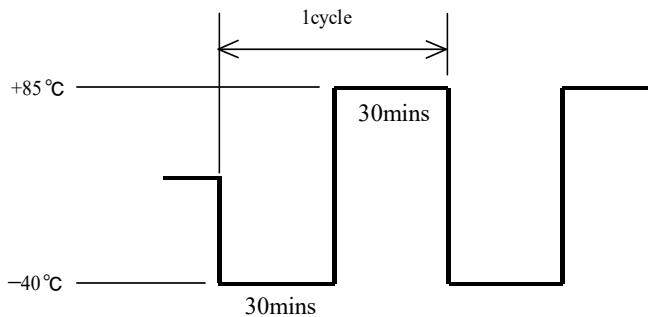
MODEL : CUS800M-12

### (1) Equipment Used (Thermal Shock Chamber)

Hitachi                    ES-77LH

### (2) Test Conditions

- Ambient Temperature : -40°C      85°C
- Test Time : 30 mins each temp.
- Test Cycle : 700 Cycles
- Not Operating



### (3) Test Method

Before testing, check if there is no abnormal output, then put the D.U.T. in testing chamber, and test it according to the above cycle. 700 cycles later, leave it for 1 hour at the room temperature , then check if there is no abnormal output.

### (4) Acceptable Conditions

No abnormal output after test.

### (5) Test Results

Judgement :      OK

## 9. FAN Life Expectancy

MODEL : CUS800M-12

### (1) Part Name

EFB0412HHDFT3 (DELTA)

### (2) Life Expectancy

The data shows fan life expectancy for fan only by manufacture(90% survival rate).  
Fig. 1 shows measuring point of fan outlet temperature.

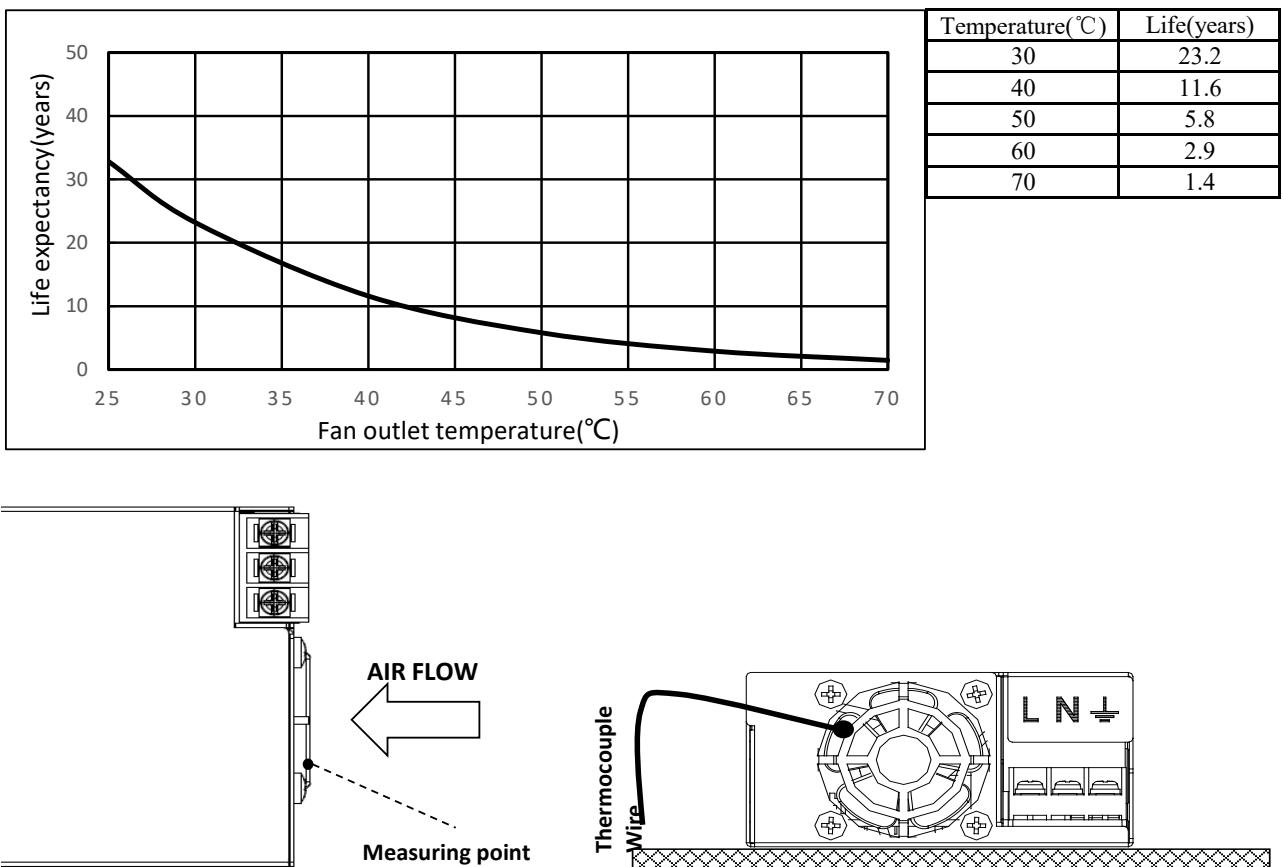


Fig.1 Measuring point of fan outlet temperature.